



2SD882

TO-92 Bipolar Transistors(NPN)

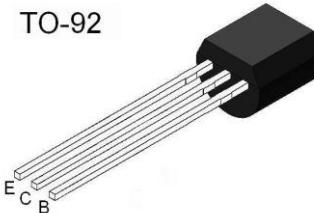


Application

- Audio Frequency Power Amplifier
- Low Speed Switching

Features

- Low saturation voltage $V_{CE(sat)}$.
- Complement to 2SB772



Absolute Maximum Ratings (Ta=25°C)

| Parameter | Symbol | Value | Unit |
|-----------------------------|------------|----------|------|
| Collector-Base Voltage | BV_{CBO} | 40 | V |
| Collector-Emitter Voltage | BV_{CEO} | 30 | V |
| Emitter-Base Voltage | BV_{EBO} | 5 | V |
| Collector Current | I_C | 1 | A |
| Collector Power Dissipation | P_C | 800 | mW |
| Junction Temperature | T_j | 150 | °C |
| Storage Temperature | T_{stg} | -55~+150 | °C |

Electrical Characteristics (Ta=25°C)

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|---------------------------------------|---------------|-----------------------------------|-----|-----|-----|---------|
| Collector-base breakdown voltage | BV_{CBO} | $I_C = 100\mu A, I_B = 0$ | 40 | | | |
| Collector-emitter breakdown voltage | BV_{CEO} | $I_C = 1mA, I_B = 0$ | 30 | | | V |
| Emitter-base breakdown voltage | BV_{EBO} | $I_E = 100\mu A, I_B = 0$ | 5 | | | V |
| Collector cut-off current | I_{CBO} | $V_{CB} = 30V, I_E = 0$ | | | 0.1 | μA |
| Emitter cut-off current | I_{EBO} | $V_{EB} = 5V, I_C = 0$ | | | 0.1 | μA |
| DC current gain* | h_{FE1} | $V_{CE} = 1V, I_C = 0.1A$ | 60 | | 400 | |
| | h_{FE2} | $V_{CE} = 1V, I_C = 0.5A$ | 20 | | | |
| Collector-emitter saturation voltage* | $V_{CE(sat)}$ | $I_C = 1A, I_B = 0.1A$ | | | 0.5 | V |
| Base-emitter saturation voltage* | $V_{BE(sat)}$ | $I_C = 1A, I_B = 0.1A$ | | | 1.2 | V |
| Transition frequency | f_T | $V_{CE} = 10V, I_B = 0.1A$ | | 90 | | MHz |
| Output Capacitance | C_{ob} | $V_{CE} = 10V, I_E = 0, f = 1MHz$ | | 45 | | pF |

* Pulse Test: PW≤350μs, Duty Cycle≤2% Pulsed

h_{FE1} Classification

| Classification | R | Q | P | E |
|----------------|--------|---------|---------|---------|
| Range | 60~120 | 100~200 | 160~320 | 200~400 |



Typical Characteristics

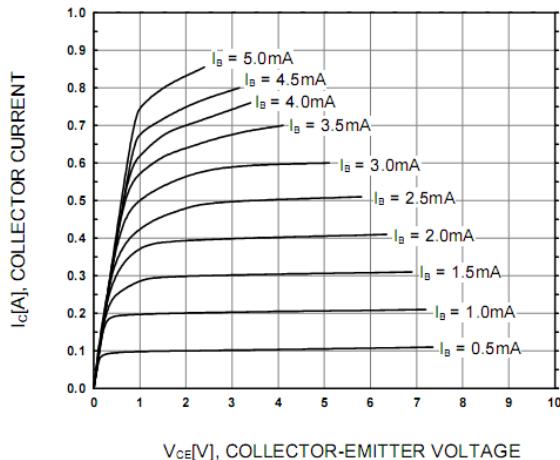


Figure.1 Static characteristics

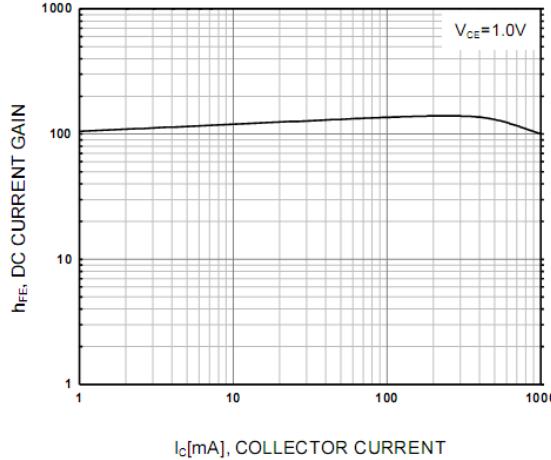


Figure.2 DC Current Gain

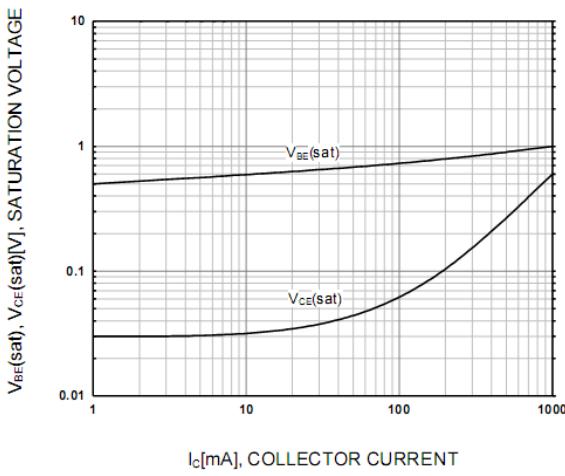


Figure.3 Saturation voltage

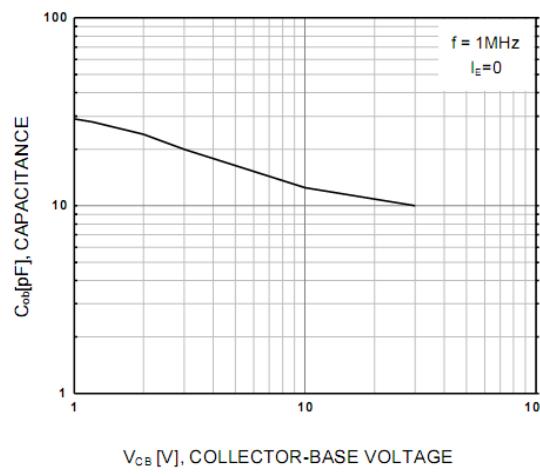


Figure 4. Collector Output Capacitance

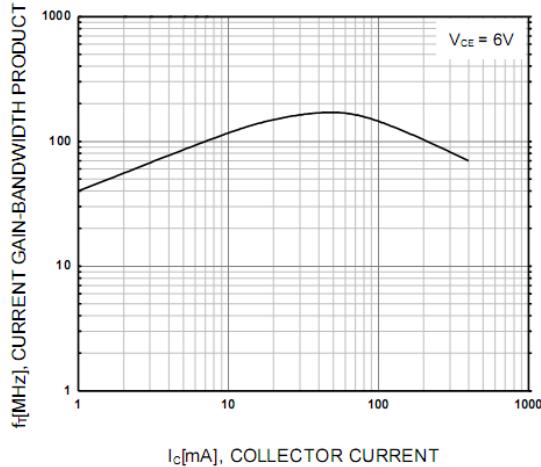


Figure.5 Current Gain-Bandwidth Product

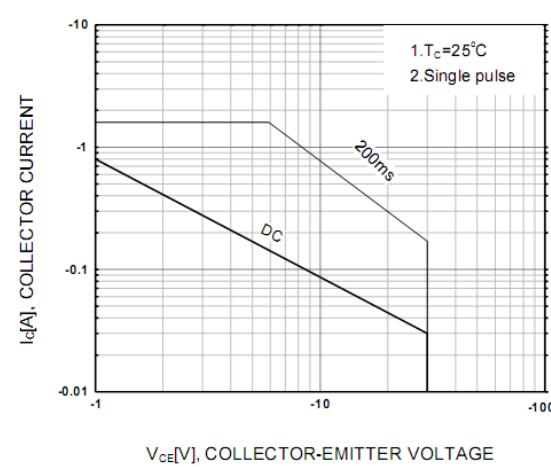


Figure.6 Safe Operation Area

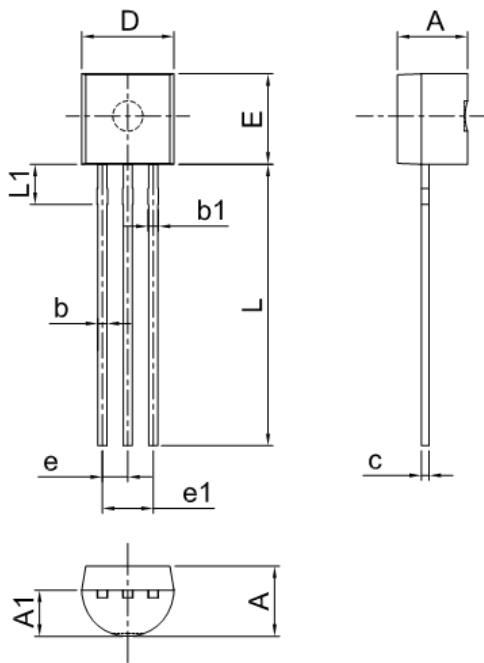


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Package Dimensions



| Dim | Millimeter | | Inches | |
|-----|------------|-------|--------|-------|
| | Min. | Max. | Min. | Max. |
| A | 3.30 | 3.70 | 0.130 | 0.146 |
| A1 | 2.30 | 2.70 | 0.091 | 0.106 |
| b | 0.40 | 0.50 | 0.016 | 0.020 |
| b1 | 0.50 | 0.70 | 0.020 | 0.028 |
| c | 0.35 | 0.45 | 0.014 | 0.018 |
| D | 4.45 | 4.70 | 0.175 | 0.185 |
| E | 4.40 | 4.65 | 0.173 | 0.183 |
| e | 1.17 | 1.37 | 0.046 | 0.054 |
| e1 | 2.34 | 2.64 | 0.092 | 0.104 |
| L | 13.50 | 14.50 | 0.531 | 0.571 |
| L1 | 1.80 | 2.20 | 0.071 | 0.087 |

| Package | Packing | Quantity | Box | Box Size(mm) | Carton | Carton Size(mm) |
|---------|---------|------------|-----------|--------------|------------|-----------------|
| TO-92 | Bulk | 1000pcs/BP | 10,000pcs | 245×170×100 | 100,000pcs | 525×375×270 |
| TO-92 | Tape | 2000pcs/TP | 2000pcs | 333×162×43 | 20,000pcs | 350×340×250 |